

3V OUTPUT RAIL TO RAIL MICROPOWER DUAL BiCMOS OPERATIONAL AMPLIFIERS

- **MICROPOWER CONSUMPTION :**
1.2µA/operator
- **RAIL TO RAIL OUTPUT VOLTAGE RANGE**
- **SINGLE SUPPLY OPERATION FROM**
2.6V TO 10V
- **EXTREMELY LOW INPUT BIAS CURRENT :**
1pA typ.
- **ESD TOLERANCE : 2kV**
- **LATCH UP IMMUNITY**

DESCRIPTION

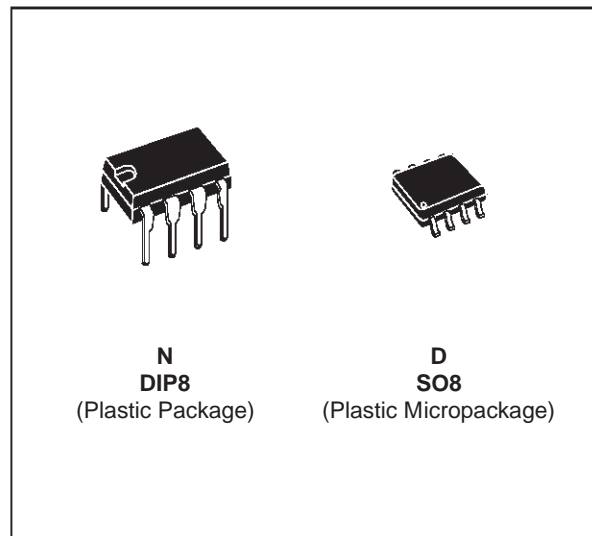
The TS942 is an output RAIL TO RAIL dual BiCMOS operational amplifier offering an extremely low consumption of 1.2µA/op.

This current is stable on the single supply operating range 2.6V to 10V.

The output reaches :

$$\square V_{CC}^+ +150mV \quad V_{CC}^- -150mV \quad \text{with } R_L = 10k\Omega$$

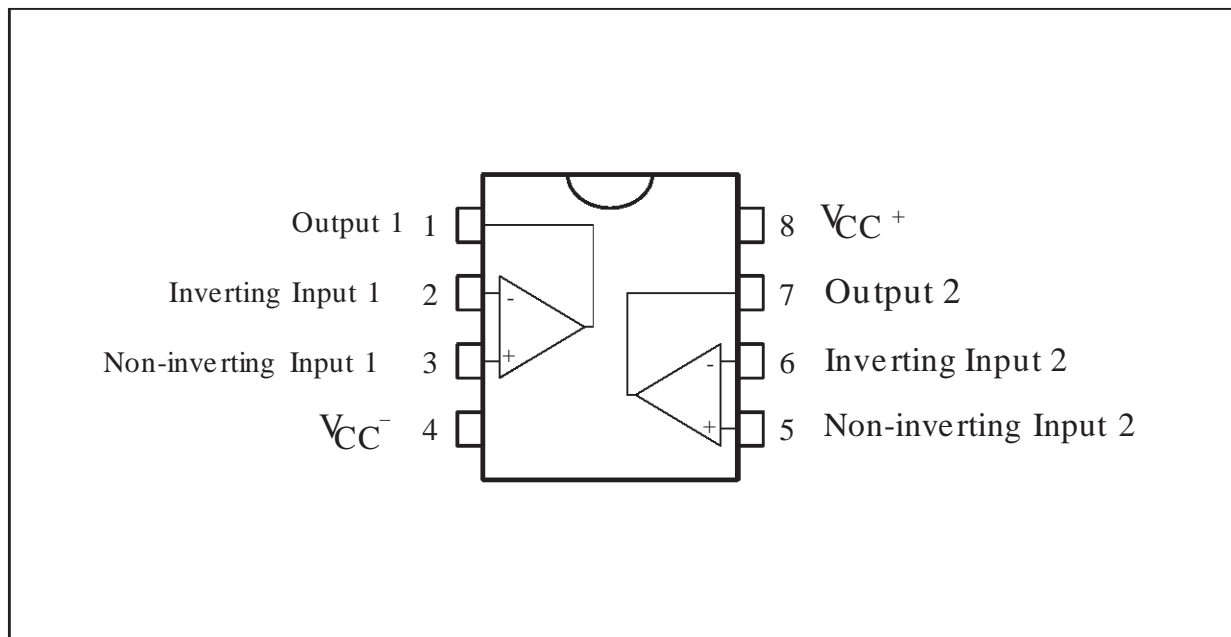
This device is particularly well suited for battery supplied systems (alarm, smoke detector, battery charge control, pH meter...).



ORDER CODES

Part Number	Temperature Range	Package	
		N	D
TS942I	-40, +85°C	•	•

PIN CONNECTIONS (top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage - (note 1)	12	V
V _{id}	Differential Input Voltage - (note 2)	±12	V
V _i	Input Voltage - (note 3)	-0.3 to V _{CC} ⁺ +0.3	V
T _{oper}	Operating Free Air Temperature Range	-40 to +85	°C
T _{stg}	Storage Temperature	-65 to +150	°C

- Notes :**
1. All voltage values, except differential voltage are with respect to network ground terminal.
 2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
 3. The magnitude of input and output voltages must never exceed V_{CC}⁺ +0.3V.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	2.6 to 10	V
V _{icm}	Common Mode Input Voltage Range	V _{CC} ⁻ -0.2 to V _{CC} ⁺ -1.3	V

ELECTRICAL CHARACTERISTICS

V_{CC}⁺ = 5V, V_{CC}⁻ = 0V, R_L connected to V_{CC}/2, T_{amb} = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{io}	Input Offset Voltage TS942 TS942A TS942B			10 5 2	mV
I _{io}	Input Offset Current - (note 1)		1	100	pA
I _{ib}	Input Bias Current - (note 1)		1	150	pA
I _{CC}	Supply Current (per operator) - no load		1.2		µA
V _{icm}	Input Common Mode Voltage Range		-0.2 to +3.8		V
A _{vd}	Large Signal Voltage Gain R _L = 1MΩ, V _o = 4Vpp		100		V/mV
V _{OH}	High Level Output Voltage V _{id} = 100mV R _L = 1MΩ R _L = 10kΩ		4.99 4.85		V
V _{OL}	Low Level Output Voltage V _{id} = -100mV R _L = 1MΩ R _L = 10kΩ		5 150		mV
CMR	Common Mode Rejection Ratio		85		dB
SVR	Supply Voltage Rejection Ratio		85		dB
I _o	Output Short Circuit Current V _{id} = ±100mV Source (V _o = V _{CC} ⁻) Sink (V _o = V _{CC} ⁺)		5 6		mA
GBP	Gain Bandwidth Product (R _L = 1MΩ, C _L = 50pF)		10		kHz
SR	Slew Rate		5		V/ms
∅ _m	Phase Margin (C _L = 50pF)		65		Degrees

Note 1 : Maximum values including unavoidable inaccuracies of the industrial test.

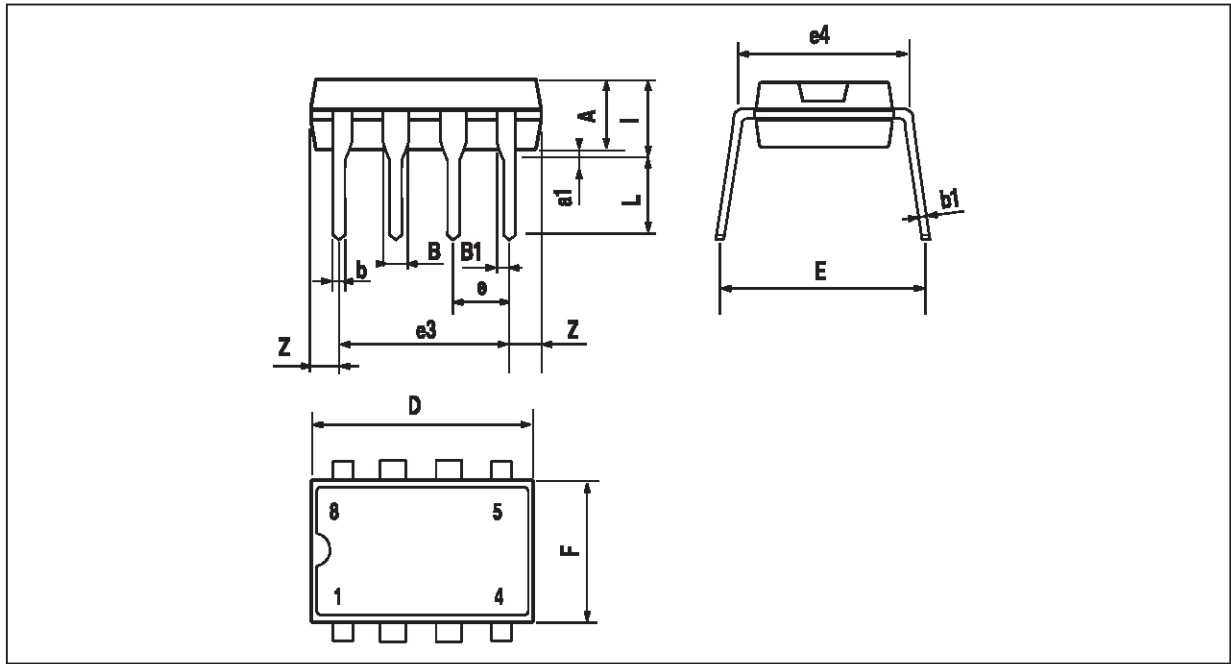
ELECTRICAL CHARACTERISTICS

$V_{CC}^+ = 3V$, $V_{CC}^- = 0V$, R_L connected to $V_{CC}/2^-$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage TS942 TS942A TS942B			10 5 2	mV
I_{io}	Input Offset Current - (note 1)		1	100	pA
I_{ib}	Input Bias Current - (note 1)		1	150	pA
I_{CC}	Supply Current (per operator) - no load		1.2		μA
V_{icm}	Input Common Mode Voltage Range		-0.2 to 1.7		V
A_{vd}	Large Signal Voltage Gain $R_L = 1M\Omega$, $V_o = 2V_{pp}$		100		V/mV
V_{OH}	High Level Output Voltage $V_{id} = 100mV$ $R_L = 1M\Omega$ $R_L = 10k\Omega$		2.99 2.85		V
V_{OL}	Low Level Output Voltage $V_{id} = -100mV$ $R_L = 1M\Omega$ $R_L = 10k\Omega$		5 100		mV
CMR	Common Mode Rejection Ratio		85		dB
SVR	Supply Voltage Rejection Ratio		85		dB
I_o	Output Short Circuit Current $V_{id} = \pm 100mV$ Source Sink ($V_o = V_{CC}^-$) ($V_o = V_{CC}^+$)		1.5 1.3		mA
GBP	Gain Bandwidth Product ($R_L = 1M\Omega$, $C_L = 50pF$)		10		kHz
SR	Slew Rate		4		V/ms
ϕ_m	Phase Margin ($C_L = 50pF$)		65		Degrees

Note 1 : Maximum values including unavoidable inaccuracies of the industrial test.

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC DIP

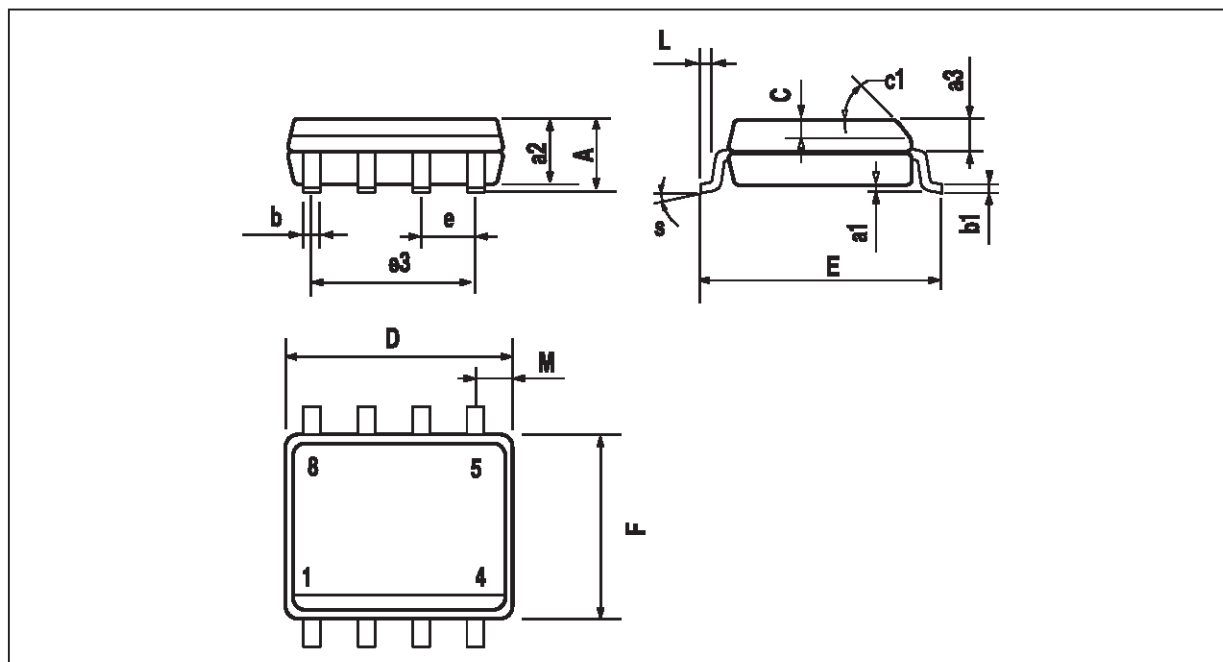


PM-DIP8.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

DIP8.TBL

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (SO)



PM-S08.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

S08.TBL

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